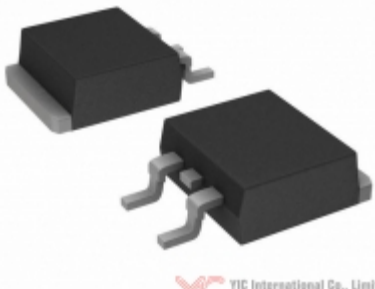



	<h2 style="color: red;">IRFBE30SPBF</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: IRFBE30SPBF
	Hersteller / Marke: Vishay / Siliconix
	Teil der Beschreibung: MOSFET N-CH 800V 4.1A D2PAK
	Datenblätter:  IRFBE30SPBF.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 2400 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	IRFBE30SPBF
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 800V 4.1A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2400 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	4.1A (Tc)
Rds On (Max) @ Id, Vgs	3 Ohm @ 2.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	78nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1300pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±20V
Verpackung	Tube

















































IRFBE30SPBF ist neu im Original, Suche IRFBE30SPBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBE30SPBF Vishay / Siliconix mit Garantie und Vertrauen.
Anfrage IRFBE30SPBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFBE30STRL Vishay / Siliconix MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30PBF Vishay / Siliconix MOSFET N-CH 800V 4.1A TO-220AB</p>	 <p>IRFBE30STRR Vishay / Siliconix MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30SPBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>
 <p>IRFBE30S Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30PBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A TO-220AB</p>	 <p>IRFBE30STRL Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30STRLPBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>

heiße Teile

Mehr

 IRFBC40LC	 IRFBC40LCPBF	 IRFBC40LCPBF	 IRFBC40LPBF	 IRFBC40LPBF
 IRFBC40S	 IRFBC40S	 IRFBC40SPBF	 IRFBC40SPBF	 IRFBC40STRL
 IRFBC40STRL	 IRFBC40STRLPBF	 IRFBC40STRLPBF	 IRFBC40STRR	 IRFBC40STRR
 IRFBC41LC	 IRFBE20PBF	 IRFBE20PBF	 IRFBE20SPBF	 IRFBE30L
 IRFBE30L	 IRFBE30LPBF-M	 IRFBE30PBF	 IRFBE30PBF	 IRFBE30SPBF
 IRFBE30STRLPBF	 IRFBE30STRLPBF	 IRFBF20LPBF	 IRFBF20LPBF	 IRFBF20STRL
 IRFBF20STRL	 IRFBF20STRLPBF	 IRFBF20STRLPBF	 IRFBG20PBF	 IRFBG20PBF
 IRFBG30PBF	 IRFBG30PBF	 IRFBL10N60A	 IRFC480LCD	 IRFD010PBF
 IRFD010PBF	 IRFD020PBF	 IRFD020PBF	 IRFD110PBF	 IRFD110PBF
 IRFD120PBF	 IRFD120PBF	 IRFD12N06RLESM	 IRFD210PBF	 IRFD210PBF

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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